

# UNISONIC TECHNOLOGIES CO., LTD

P1888 **Preliminary CMOS IC** 

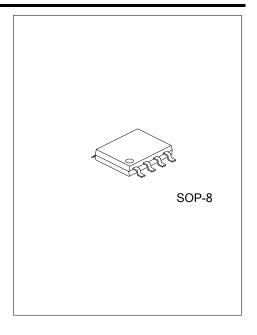
# **PWM CONTROL 3A** STEP-DOWN CONVERTER

#### DESCRIPTION

UTC P1888 consists of 3A step-down switching regulator control which includes a reference voltage source, oscillation circuit, error amplifier, internal PMOS and etc with PWM.

UTC P1888 can provide low-ripple power, high efficiency, and excellent transient characteristics and an enable function, an over current protect function and a short circuit protect function are built inside, so the operation frequency will be reduced from 300KHz to 30KHz when OCP or SCP happens. And the PWM control circuit can vary the duty ratio linearly from 100 down to 0%. This converter also includes an error amplifier circuit as well as a soft-start circuit that prevents overshoot at startup. Also, to minimum external component count an internal compensation block is built in.

UTC P1888 can work as step-down switching regulators with the addition of an internal P-channel Power MOS, a coil, capacitors, and a diode connected externally. It provides such outstanding features: low current consumption. It is also suitable for the operation via an AC adapter because this converter can accommodate an input voltage up to 23V.

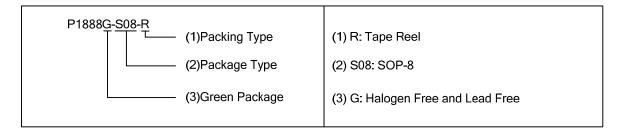


#### **FEATURES**

- \* Soft-start, Current Limit, Enable function
- \* Thermal Shutdown function
- \* Built-in internal SW P-channel MOS
- \* Input voltage: 4V~23V. \* Output voltage: 1.23V~V<sub>CC</sub>.
- \* Duty ratio: 0% to 100% PWM control
- \* Oscillation frequency: 300KHz typ.

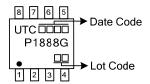
#### ORDERING INFORMATION

Ordering Number	Package	Packing	
P1888G-S08-R	SOP-8	Tape Reel	

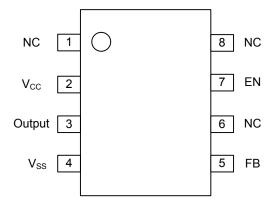


www.unisonic.com.tw 1 of 4

# ■ MARKING



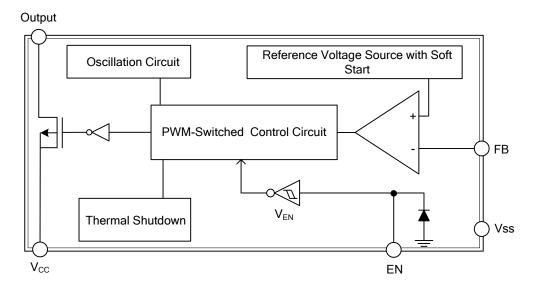
#### **■ PIN CONFIGURATION**



# **■ PIN DESCRIPTION**

PIN NO.	PIN NAME	DESCRIPTION		
2	$V_{CC}$	IC power supply pin		
3	Output	Switch Pin. Connect external inductor/diode here. Minimize trace area at this pin to reduce EMI.		
4	$V_{SS}$	GND		
5	FB	Feedback pin.		
7	EN	Power-off pin H: Normal operation (Step-down operation) L: Step-down operation stopped (All circuits deactivated)		

# ■ BLOCK DIAGRAM



# ■ ABSOLUTE MAXIMUM RATING

PARAMETER	SYMBOL	RATINGS	UNIT
V <sub>CC</sub> Pin Voltage	$V_{CC}$	V <sub>SS</sub> -0.3~V <sub>SS</sub> +25	V
Feedback Pin Voltage	$V_{FB}$	V <sub>SS</sub> -0.3~V <sub>CC</sub>	<b>V</b>
EN Pin Voltage	$V_{EN}$	V <sub>SS</sub> -0.3~V <sub>IN</sub> +0.3	V
Switch Pin Voltage	V <sub>OUTPUT</sub>	V <sub>SS</sub> -0.3~V <sub>IN</sub> +0.3	V
Power Dissipation	$P_{D}$	Internally limited	mW
Operating Ambient Temperature	Ta	-20~+85	°C
Operating Temperature	T <sub>OPR</sub>	-20~+125	°C
Storage Temperature	T <sub>STG</sub>	-40~+150	°C

Note: Absolute maximum ratings are those values beyond which the device could be permanently damaged. Absolute maximum ratings are stress ratings only and functional device operation is not implied.

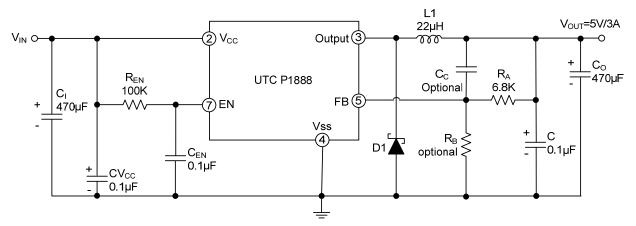
#### **■ THERMAL DATA**

PARAMETER	SYMBOL	RATINGS	UNIT
Junction to Ambient	$\theta_{JA}$	134	°C/W
Junction to Case	$\theta_{JC}$	22	°C/W

# ■ ELECTRICAL CHARACTERISTICS (T<sub>a</sub>=25°C, V<sub>IN</sub>=12V, unless otherwise specified)

PARAMETER	SYMBOL	CONDITIONS		TYP.	MAX.	UNIT
Input Voltage	$V_{IN}$				23	V
Feedback Voltage	$V_{FB}$	I <sub>OUT</sub> =0.1A	1.18	1.23	1.28	V
Feedback Bias Current	I <sub>FB(BIAS)</sub>	I <sub>OUT</sub> =0.1A		0.1		μΑ
Switch Current	I <sub>SW</sub>		3.1			Α
Standby Current	I <sub>STN-BY</sub>	V <sub>EN</sub> =0V		10		μΑ
Line Regulation	<u>Δ</u> Vουτ	V <sub>IN</sub> =5V~23V, I <sub>OUT</sub> =0.2A		1		%
Load Regulation	<u>Δ</u> Vουτ	I <sub>OUT</sub> =0.1~3A		0.2		%
Oscillation Frequency	fosc	Measure waveform at SW pin		300	360	KHz
Frequency of Current Limit or Short Circuit Protect	f <sub>OSC1</sub>	Measure waveform at SW pin	10			KHz
EN Pin Input Voltage	V <sub>SH</sub>	Evaluate oscillation at SW pin		0.79		V
EN FIII IIIput Voltage	V <sub>SL</sub>	Evaluate oscillation stop at SW pin		0.72		V
EN Pin Input Leakage Current	I <sub>SH</sub>			20		μΑ
	I <sub>SL</sub>			-10		μΑ
Soft-Start Time	T <sub>SS</sub>		0.3	2	5	ms
Internal MOSEET D	R <sub>DS(ON)</sub>	V <sub>IN</sub> =5V, V <sub>FB</sub> =0V		110	150	mΩ
Internal MOSFET R <sub>DS(ON)</sub>		V <sub>IN</sub> =12V, V <sub>FB</sub> =0V		70	100	mΩ
Efficiency	η	V <sub>IN</sub> =12V, V <sub>OUT</sub> =5V, I <sub>OUT</sub> =3A		88		%

#### **■ TYPICAL APPLICATION CIRCUIT**



Note:  $V_{OUT} = V_{FB} x (1+R_A/R_B)$ ,  $R_B=0.7K\sim5K$  ohm

V <sub>IN</sub> =12V, I <sub>MAX</sub> =3A				
$V_{OUT}$	2.5V	3.3V	5V	
L <sub>1</sub> Value	15µH	18µH	22µH	

UTC assumes no responsibility for equipment failures that result from using products at values that exceed, even momentarily, rated values (such as maximum ratings, operating condition ranges, or other parameters) listed in products specifications of any and all UTC products described or contained herein. UTC products are not designed for use in life support appliances, devices or systems where malfunction of these products can be reasonably expected to result in personal injury. Reproduction in whole or in part is prohibited without the prior written consent of the copyright owner. The information presented in this document does not form part of any quotation or contract, is believed to be accurate and reliable and may be changed without notice.